

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	0	(high voltage) and (p well) and (n well) and (field stop implant) and (pick up region) and @ad<"20030312"	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2005/02/1 6 10:39
2	BRS	L2	0	(high voltage) and (p well) and (n well) and (field stop implant) and @ad<"20030312"	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2005/02/1 6 10:40
3	BRS	L3	0	(high voltage) and (p-well) and (n-well) and (field stop implant) and @ad<"20030312"	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2005/02/1 6 10:41
4	BRS	L4	1756	(high voltage) and (p-well) and (n-well) and @ad<"20030312"	US- PGPUB ; USPAT ; EPO; JPO; DERWE NT; IBM_T DB	2005/02/1 6 10:56

	Type	L #	Hits	Search Text	DBs	Time Stamp
5	BRS	L5	2	4 and (field stop)	US-PGPUB; USPAT; EPO; JPO; DERWE NT; IBM_T DB	2005/02/16 10:42
6	BRS	L6	2232	(high voltage) and (p well) and (n well) and @ad<"20030312"	US-PGPUB; USPAT; EPO; JPO; DERWE NT; IBM_T DB	2005/02/16 10:57
7	BRS	L7	2	6 and (field stop)	US-PGPUB; USPAT; EPO; JPO; DERWE NT; IBM_T DB	2005/02/16 10:59
8	BRS	L8	15	cmos and (high voltage) and (field stop) and @ad<"20030312"	US-PGPUB; USPAT; EPO; JPO; DERWE NT; IBM_T DB	2005/02/16 11:01

	Type	L #	Hits	Search Text	DBs	Time Stamp
9	BRS	L9	3351	cmos and (pick up)	US-PGPUB; USPAT; EPO; JPO; DERWE NT; IBM_T DB	2005/02/16 11:44
10	BRS	L10	37	9 and (field stop)	US-PGPUB; USPAT; EPO; JPO; DERWE NT; IBM_T DB	2005/02/16 11:44
11	BRS	L11	18	cmos and (pick up region)	US-PGPUB; USPAT; EPO; JPO; DERWE NT; IBM_T DB	2005/02/16 11:46
12	BRS	L12	11	11 and @ad<"20030312"	US-PGPUB; USPAT; EPO; JPO; DERWE NT; IBM_T DB	2005/02/16 11:46